

Search History

L Number	Hits	Search Text	DB	Time stamp
1	311608	nonvolatile or eeprom or flash	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:43
2	40615	sense near2 amplifier	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:43
3	1093170	program\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:44
4	70103	(bit near line) or bitline	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:45
5	23046	select\$4 near2 transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:45
6	66737	program\$4 near2 operation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:46
7	26336	(program\$4 near2 operation) with control\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:46
8	1397594	"one time" or once	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:46
9	103665	("one time" or once) with (perform\$4 or execut\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:47
10	8216	cell near9 sandwich\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:47
11	8942	((nonvolatile or eeprom or flash) and (sense near2 amplifier))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:48
12	5782	((nonvolatile or eeprom or flash) and (sense near2 amplifier)) and program\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:48
13	4152	((nonvolatile or eeprom or flash) and (sense near2 amplifier)) and program\$4 and ((bit near line) or bitline)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:48

14	1750	(((((nonvolatile or eeprom or flash) and (sense near2 amplifier)) and program\$4) and ((bit near line) or bitline)) and (select\$4 near2 transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:48
15	973	(((((nonvolatile or eeprom or flash) and (sense near2 amplifier)) and program\$4) and ((bit near line) or bitline)) and (select\$4 near2 transistor) and (program\$4 near2 operation))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:48
16	525	(((((nonvolatile or eeprom or flash) and (sense near2 amplifier)) and program\$4) and ((bit near line) or bitline)) and (select\$4 near2 transistor) and (program\$4 near2 operation) and ((program\$4 near2 operation) with control\$4))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:48
17	342	((((((nonvolatile or eeprom or flash) and (sense near2 amplifier)) and program\$4) and ((bit near line) or bitline)) and (select\$4 near2 transistor)) and (program\$4 near2 operation) and ((program\$4 near2 operation) with control\$4)) and ("one time" or once)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:48
18	95	((((((nonvolatile or eeprom or flash) and (sense near2 amplifier)) and program\$4) and ((bit near line) or bitline)) and (select\$4 near2 transistor)) and (program\$4 near2 operation) and ((program\$4 near2 operation) with control\$4)) and ("one time" or once) and (("one time" or once) with (perform\$4 or execut\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:49
19	10	((((((nonvolatile or eeprom or flash) and (sense near2 amplifier)) and program\$4) and ((bit near line) or bitline)) and (select\$4 near2 transistor)) and (program\$4 near2 operation) and ((program\$4 near2 operation) with control\$4)) and ("one time" or once) and (("one time" or once) with (perform\$4 or execut\$3))) and (cell near9 sandwich\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/03 08:49